TOSHIBA GTR Module Silicon N Channel IGBT

# MG150Q2YS40

### High Power Switching applications Motor Control Applications

• High input impedance

• High speed :  $t_f = 0.5 \mu s \text{ (max)}$ 

 $t_{rr} = 0.5 \mu s \text{ (max)}$ 

Low saturation voltage

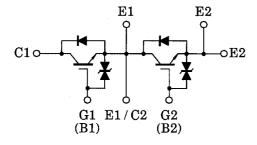
:  $V_{CE (sat)} = 4.0V (max)$ 

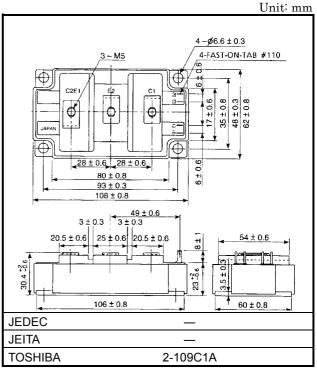
• Enhancement-mode

• Includes a complate half bridge in one package.

The electrodes are isolated from case.

#### **Equivalent Circuit**





Weight: 430g (typ.)

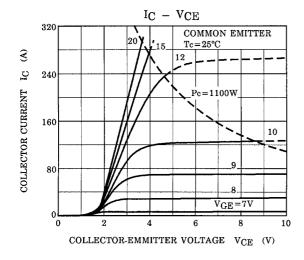
#### **Maximum Ratings (Ta = 25°C)**

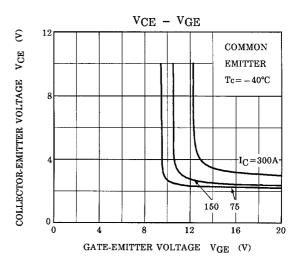
Characteristics		Symbol	Rating	Unit	
Collector-emitter voltage		$V_{CES}$	1200	V	
Gate-emitter voltage		V <sub>GES</sub>	±20	V	
Collector current	DC	IC	150	Α	
	1ms	I <sub>CP</sub>	300		
Forward current	DC	lF	150	Α	
	1ms	I <sub>FM</sub>	300		
Collector power dissipation (Tc = 25°C)		PC	1100	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	<b>-</b> 40 ~ 125	°C	
Isolation voltage		V <sub>Isol</sub>	2500 (AC 1 min.)	V	
Screw torque (Terminal / mounting)		_	3/3	N·m	

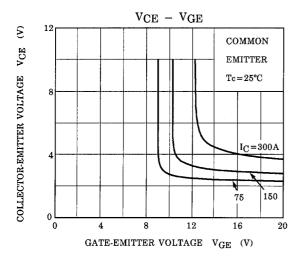
## Electrical Characteristics (Ta = 25°C)

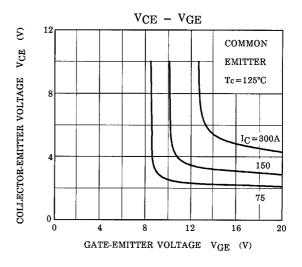
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GES</sub>	V <sub>GE</sub> = ±20V, V <sub>CE</sub> = 0	_	_	±20	μΑ
Collector cut-off current		I <sub>CES</sub>	V <sub>CE</sub> = 1200V, V <sub>GE</sub> = 0		_	2.0	mA
Gate-emitter cut-off voltage		V <sub>GE (off)</sub>	I <sub>C</sub> = 150mA , V <sub>CE</sub> = 5V	3.0	_	6.0	V
Collector-emitter saturation voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = 150A, V <sub>GE</sub> = 15V	_	3.0	4.0	V
Input capacitance		C <sub>ies</sub>	V <sub>CE</sub> = 10V, V <sub>GE</sub> = 0, f = 1MHz	_	18000	_	pF
Switching time	Rise time	t <sub>r</sub>	5.6Ω 0 — 5.6Ω 15V 0 — 600V	_	0.3	0.6	- µs
	Turn-on time	t <sub>on</sub>		_	0.4	0.8	
	Fall time	t <sub>f</sub>			0.2	0.5	
	Turn-off time	t <sub>off</sub>			0.8	1.5	
Forward voltage		V <sub>F</sub>	I <sub>F</sub> = 150A, V <sub>GE</sub> = 0		2.0	3.0	V
Reverse recovery time		t <sub>rr</sub>	I <sub>F</sub> = 150A, V <sub>GE</sub> = -10V di / dt = 200A / μs	_	0.25	0.5	μs
Thermal resistance		R <sub>th (j-c)</sub>	Transistor	— — 0.1°		0.11	°C/W
			Diode	_	_	0.4	C/W

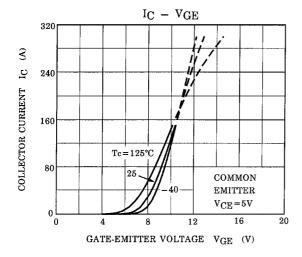
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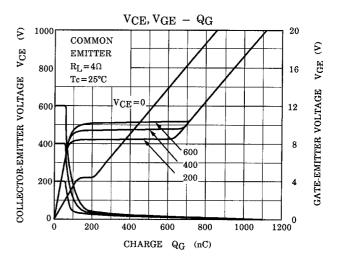




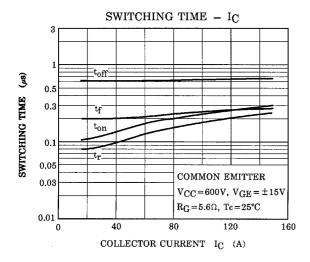


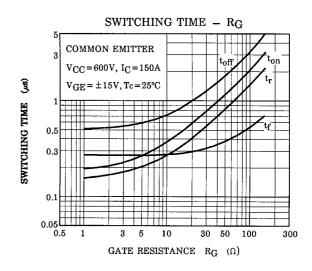


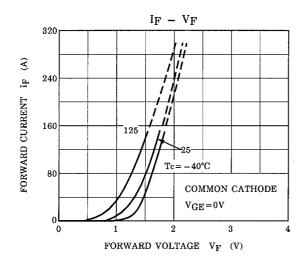


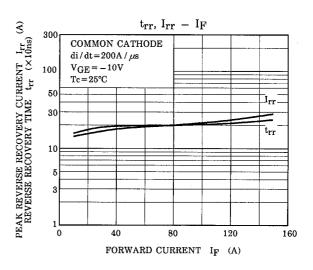


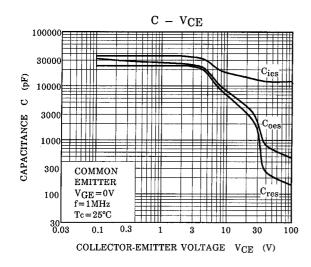
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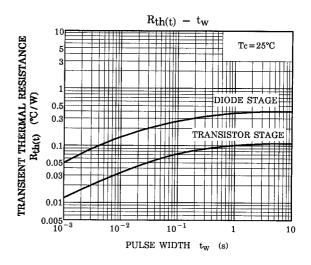




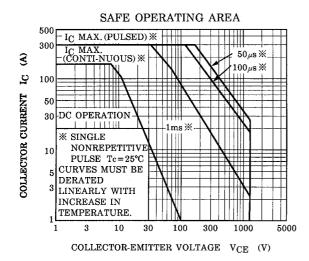


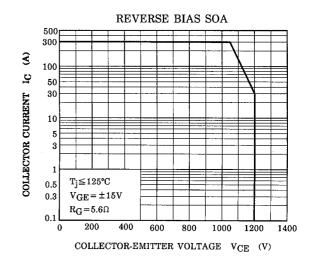






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